

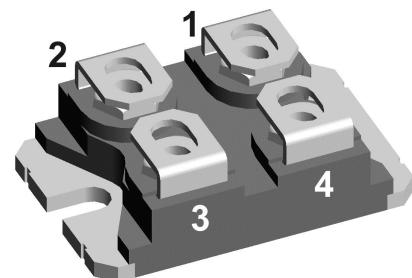
# FRED

$V_{RRM}$  = 200 V  
 $I_{FAV}$  = 2x 60 A  
 $t_{rr}$  = 20 ns

**Fast Recovery Epitaxial Diode**  
**Low Loss and Soft Recovery**  
**Parallel legs**

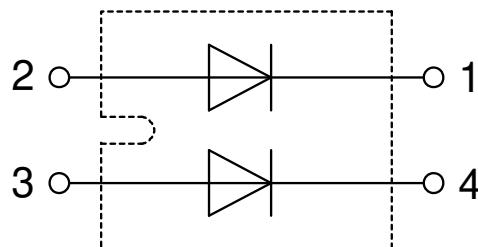
**Part number**

**DSEI2x61-02A**



Backside: isolated

 E72873



## Features / Advantages:

- Planar passivated chips
- Low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

## Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

## Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling

## Disclaimer Notice

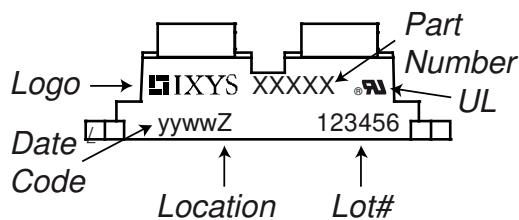
Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).

**Fast Diode**

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			200	V
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			200	V
$I_R$	reverse current, drain current	$V_R = 200 \text{ V}$ $V_R = 160 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		50 11	$\mu\text{A}$ mA
$V_F$	forward voltage drop	$I_F = 60 \text{ A}$ $I_F = 120 \text{ A}$ $I_F = 60 \text{ A}$ $I_F = 120 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1.07 1.25 0.91 1.15	V V
$I_{FAV}$	average forward current	$T_C = 100^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 150^\circ\text{C}$		60	A
$V_{F0}$ $r_F$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 150^\circ\text{C}$		0.69 3.7	V $\text{m}\Omega$
$R_{thJC}$	thermal resistance junction to case				0.7	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.10		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ\text{C}$		180	W
$I_{FSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		950	A
$C_J$	junction capacitance	$V_R = 200 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		170	pF
$I_{RM}$	max. reverse recovery current		$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 100^\circ\text{C}$		6.5 11	A A
$t_{rr}$	reverse recovery time	$I_F = 70 \text{ A}; V_R = 100 \text{ V}$ $-di_F/dt = 400 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 100^\circ\text{C}$		20 50	ns ns

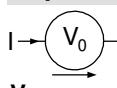
**Package SOT-227B (minibloc)**

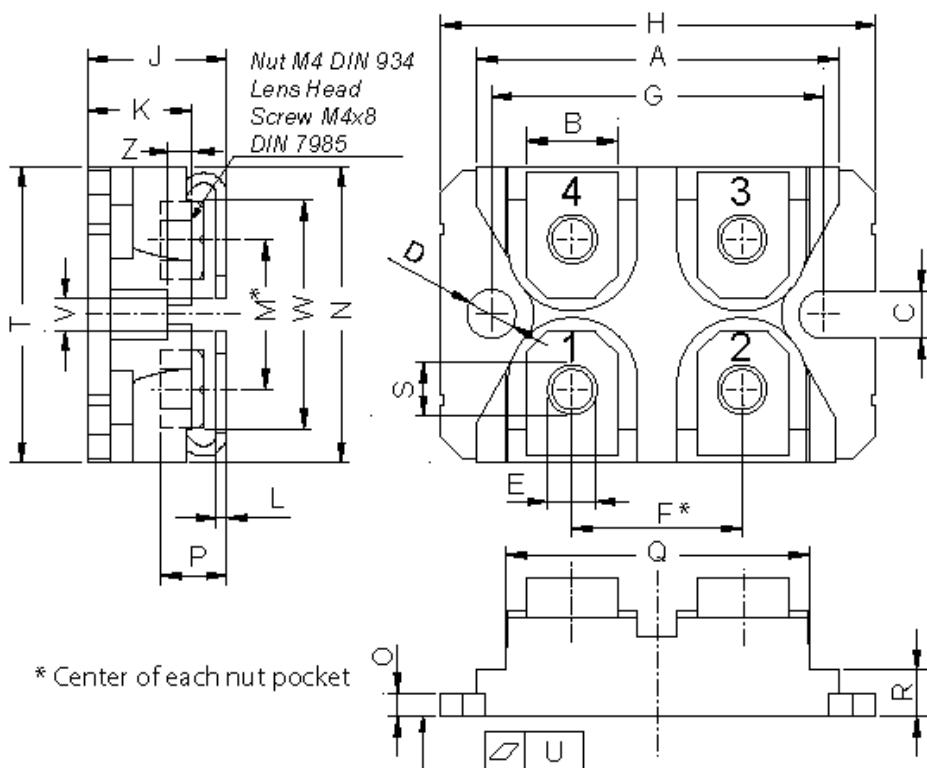
Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$I_{RMS}$	$RMS$ current	per terminal			150	A
$T_{VJ}$	virtual junction temperature		-40		150	°C
$T_{op}$	operation temperature		-40		125	°C
$T_{stg}$	storage temperature		-40		150	°C
<b>Weight</b>				30		g
$M_D$	mounting torque		1.1		1.5	Nm
$M_T$	terminal torque		1.1		1.5	Nm
$d_{Spp/App}$	creepage distance on surface / striking distance through air	terminal to terminal	10.5	3.2		mm
$d_{Spb/Apb}$		terminal to backside	8.6	6.8		mm
$V_{ISOL}$	isolation voltage	t = 1 second t = 1 minute 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	3000 2500			V V

**Product Marking**


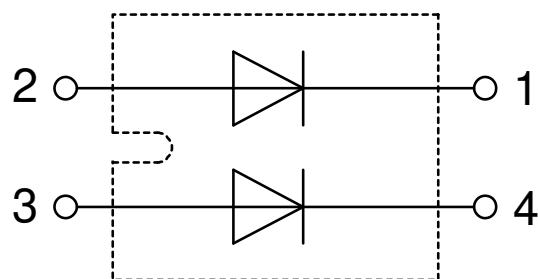
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEI2x61-02A	DSEI2x61-02A	Tube	10	469769

**Equivalent Circuits for Simulation**
\* on die level
 $T_{VJ} = 150^\circ\text{C}$ 

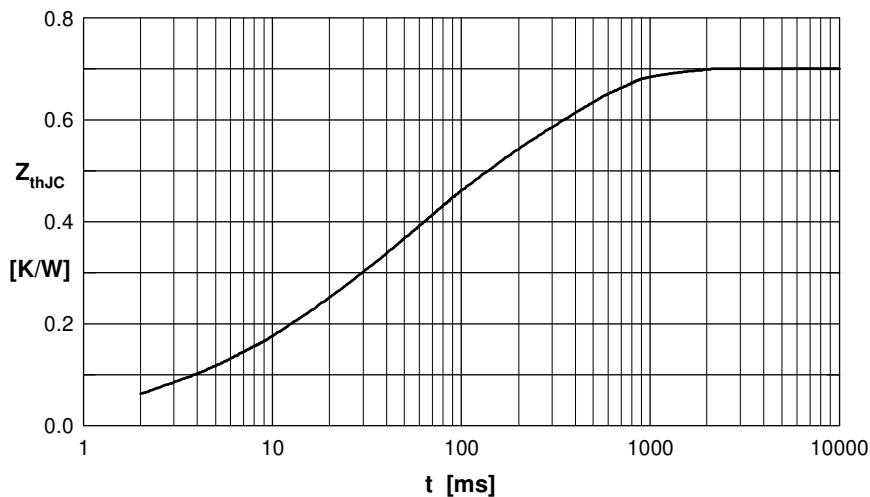
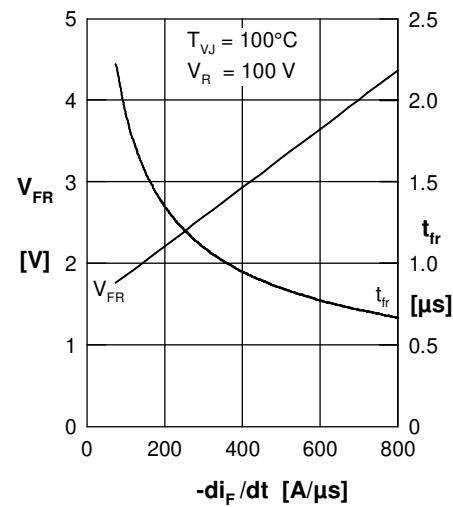
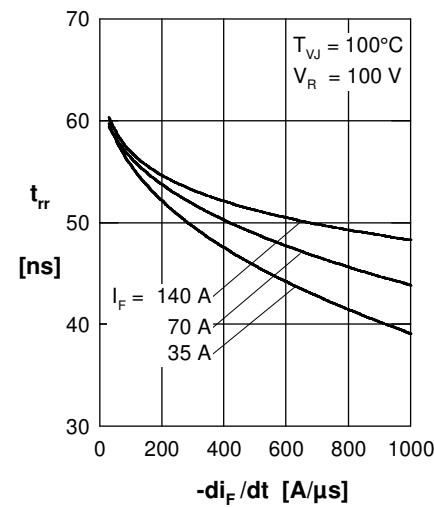
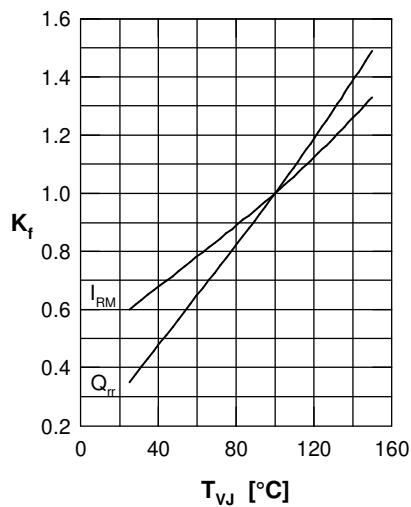
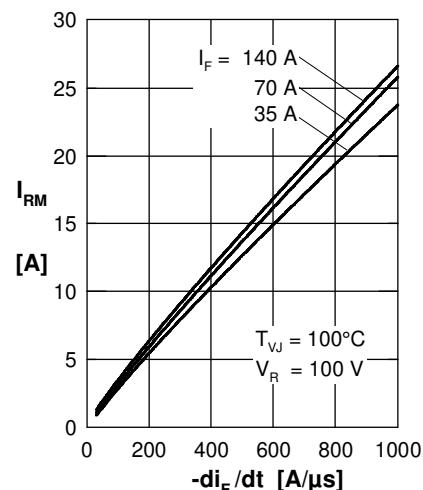
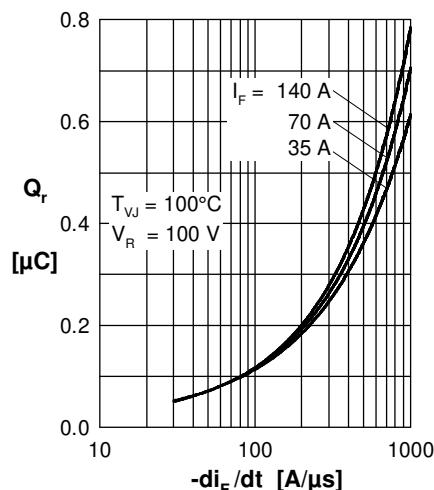
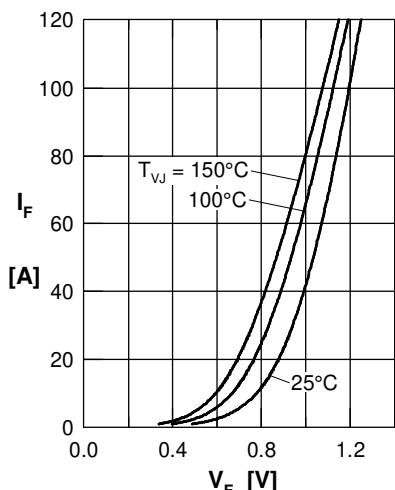
	$V_0$	$R_0$	Fast Diode	
$V_{0\max}$	threshold voltage	0.69		V
$R_{0\max}$	slope resistance *	1.8		$\text{m}\Omega$

**Outlines SOT-227B (minibloc)**


Dim.	Millimeter		Inches	
	min	max	min	max
A	31.50	31.88	1.240	1.255
B	7.80	8.20	0.307	0.323
C	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
H	37.80	38.23	1.488	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.74	0.84	0.029	0.033
M	12.50	13.10	0.492	0.516
N	25.15	25.42	0.990	1.001
O	1.95	2.13	0.077	0.084
P	4.95	6.20	0.195	0.244
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.167
S	4.55	4.85	0.179	0.191
T	24.59	25.25	0.968	0.994
U	-0.05	0.10	-0.002	0.004
V	3.20	5.50	0.126	0.217
W	19.81	21.08	0.780	0.830
Z	2.50	2.70	0.098	0.106



### Fast Diode



Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.120	0.010
2	0.045	0.002
3	0.105	0.050
4	0.160	0.050
5	0.270	0.350

# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

***Click to view similar products for Rectifiers category:***

***Click to view products by IXYS manufacturer:***

Other Similar products are found below :

[70HFR40](#) [RL252-TP](#) [150KR30A](#) [1N5397](#) [NTE5841](#) [NTE6038](#) [SCF5000](#) [1N4002G](#) [1N4005-TR](#) [JANS1N6640US](#) [481235F](#)  
[RRE02VS6SGTR](#) [067907F](#) [MS306](#) [70HF40](#) [T85HFL60S02](#) [US2JFL-TP](#) [A1N5404G-G](#) [ACGRA4007-HF](#) [ACGRB207-HF](#)  
[CLH03\(TE16L,Q\)](#) [ACGRC307-HF](#) [ACEFC304-HF](#) [NTE6356](#) [NTE6359](#) [NTE6002](#) [NTE6023](#) [NTE6039](#) [NTE6077](#) [85HFR60](#) [40HFR60](#)  
[VS-88-7272PBF](#) [70HF120](#) [85HFR80](#) [D126A45C](#) [SCF7500](#) [D251N08B](#) [SCHJ22.5K](#) [SM100](#) [SCPA2](#) [SCH10000](#) [SDHD5K](#) [VS-](#)  
[12FL100S10](#) [ACGRA4001-HF](#) [D1821SH45T PR](#) [D1251S45T](#) [NTE5990](#) [NTE6358](#) [NTE6162](#) [NTE5998](#)